

Schottky barrier (double) diodes

BAS70 series

FEATURES

- Low forward current
- High breakdown voltage
- Guard ring protected
- Small SMD package
- Low diode capacitance.

APPLICATIONS

- Ultra high-speed switching
- Voltage clamping
- Protection circuits.

DESCRIPTION

Planar Schottky barrier diodes with an integrated guard ring for stress protection. Single diodes and double diodes with different pinning are available.

The diodes BAS70, BAS70-04, BAS70-05 and BAS70-06 are encapsulated in a SOT23 small plastic SMD package. The BAS70-07 is encapsulated in a SOT143 small plastic SMD package.

MARKING

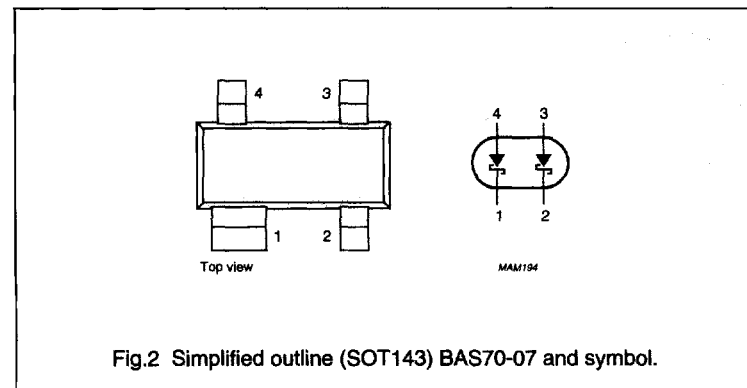
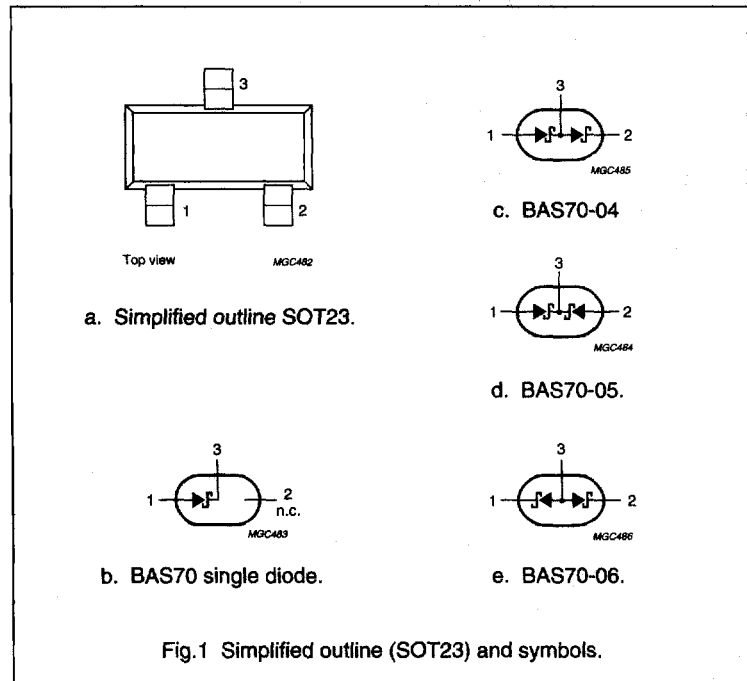
TYPE NUMBER	MARKING CODE
BAS70	73p
BAS70-04	74p
BAS70-05	75p
BAS70-06	76p
BAS70-07	77p

PINNING SOT143 (see Fig.2)

PIN	DESCRIPTION
BAS70-07	
1	k ₁
2	k ₂
3	a ₂
4	a ₁

PINNING SOT23 (see Fig.1a)

PIN	DESCRIPTION			
	BAS70 (see Fig.1b)	BAS70-04 (see Fig.1c)	BAS70-05 (see Fig.1d)	BAS70-06 (see Fig.1e)
1	a ₁	a ₁	a ₁	k ₁
2	n.c.	k ₂	a ₂	k ₂
3	k ₁	k ₁ , a ₂	k ₁ , k ₂	a ₁ , a ₂



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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per diode					
V_R	continuous reverse voltage		–	70	V
I_F	continuous forward current		–	70	mA
I_{FRM}	repetitive peak forward current	$t_p \leq 1$ s; $\delta \leq 0.5$	–	70	mA
I_{FSM}	non-repetitive peak forward current	$t_p < 10$ ms	–	100	mA
T_{stg}	storage temperature		–65	+150	°C
T_j	junction temperature		–	150	°C
T_{amb}	operating ambient temperature		–65	+150	°C

ELECTRICAL CHARACTERISTICS $T_{amb} = 25$ °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
Per diode				
V_F	forward voltage	see Fig.3 $I_F = 1$ mA $I_F = 10$ mA $I_F = 15$ mA	410 750 1	mV mV V
I_R	reverse current	$V_R = 50$ V; note 1; see Fig.4	100	nA
		$V_R = 70$ V; note 1; see Fig.4	10	μA
τ	charge carrier life time (Krakauer method)	$I_F = 5$ mA	100	ps
C_d	diode capacitance	$f = 1$ MHz; $V_R = 0$ V; see Fig.6	2	pF

Note

1. Pulsed test: $t_p = 300$ μs; $\delta = 0.02$.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-a}$	thermal resistance from junction to ambient	note 1	500	K/W

Note

1. Refer to SOT23 or SOT143 standard mounting conditions.

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GRAPHICAL DATA

